

STIC Search Report

STIC Database Tracking Number: 189950

TO: Eric W Thomas Location: jef 10d19

Art Unit: 2831

Friday, May 19, 2006

Case Serial Number: 10/534703

From: Mary S. Mims Location: STIC-EIC2800

JEF-4B59 Phone: 25928

Email: Mary.Mims@uspto.gov

Search Notes

Examiner Eric Thomas,

Please find attached results of your search for 10/534703. The search was conducted using databases on STN for microstructures. The tagged documents appear to be the closest documents located during our search. Please review all of the results.

Based on this, if you have questions or would like a refocused search, please contact me.

Thanks

Mary S. Mims





STIC Search Results Feedback Form

EIC 2800

Questions about the scope or the results of the search? Contact the EIC searcher or contact:

Jeff Harrison, EIC 2800 Team Leader 571-272-2511, JEF 4B68

Voluntary Results Feedback Form
> I am an examiner in Workgroup: Example: 2810
> Relevant prior art found , search results used as follows:
☐ 102 rejection
☐ 103 rejection
☐ Cited as being of interest.
Helped examiner better understand the invention.
☐ Helped examiner better understand the state of the art in their technology.
Types of relevant prior art found:
☐ Foreign Patent(s)
 Non-Patent Literature (journal articles, conference proceedings, new product announcements etc.)
> Relevant prior art not found:
Results verified the lack of relevant prior art (helped determine patentability).
Results were not useful in determining patentability or understanding the invention.
Comments:

Drop off or send completed forms to STIC/IZIC2300, GP4-9C13



Pord 5/15/06 2:30

189950	
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	Rev. 3/15/2004 This is an experimental format Please give suggestions or comments to Jeff Harrison, JEF-4B68, 272-2511.			
	Date 5/15/06 Serial # 10/534703 Priority Application Date 11/18/02			
	Your Name Enothomas Examiner # 76204			
	AU 2831 Phone 2-1985 Room 10 D19			
	In what format would you like your results? Paper is the default. PAPER DISK EMAIL			
	If submitting more than one search, please prioritize in order of need.			
	The EIC searcher normally will contact you before beginning a prior art search. If you would like to sit with a searcher for an interactive search, please notify one of the searchers.			
	Where have you searched so far on this case? Circle: USPT DWPI EPO Abs IPO Abs Other:			
	What relevant art have you found so far? Please attach pertinent citations or			
	Information Disclosure Statements. <u>See Attached E.P. Document.</u>			
	What types of references would you like? Please checkmark: Primary RefsX			
	What is the topic, such as the <u>novelty</u> , motivation, utility, or other specific facets defining the desired <u>focus</u> of this search? Please include the concepts, synonyms, keywords, acronyms, registry numbers, definitions, structures, strategies, and anything else that helps to describe the topic. Please attach a copy of the abstract and pertinent claims.			
A	3Nb-Al Powder comprising Adentritic microstructures			
	principally containing NbAlz, Nb2 Al, Nb3 Al, or Nb			
	and3) matrices containing Al or entectic structures containing			
	at least two selected from the group NBA13, Nb, Al.			
	N/03 A) Nb; the particles are covered with an oxide (dielect).			
	and the matrices sullounding the dendritic microstratures			
١.	The method according to a claim 12.			
	Thanks			
L	Staff-Use Only A A Type of Search Vendors			
	Searcher: Type of Search Vendors Searcher: Structure (#) STN			
	Searcher Phone: 25926 Bibliographic Dialog			
	Searcher Location: STIC-EIC2800, JEF-4B68 Litigation Questel/Orbit Date Searcher Picked Up: 5/19106 Fulltext Lexis-Nexis			
	Date Completed: 5 19 06 Patent Family WWW/Internet			
	Searcher Prep/Rev Time: 300 Other Other			
	Online Time:			

Thomas, Eric W.

From:

Spar, Steven

Sent:

Monday, May 15, 2006 11:59 AM

To:

Thomas, Eric W.

Subject:

RE: Can you help me out.

Hi Eric,

The '806 reference mentions an Al-Nb alloy on the upper right column of page 2, and the '212 reference mentions an Al-Nb alloy on the lower left column of page 2, but neither mention dendrite microstructures or capacitors.

Steve Spar

Technical Translator, Translations Branch Madison West 1A79

Phone: (571) 272-2574 Fax: (571) 273-2574

-----Original Message-----

From:

Thomas, Eric W.

Sent:

Monday, May 15, 2006 11:22 AM

To:

Spar, Steven

Subject:

Can you help me out.

Steve,

Good morning. I was wondering if you could take a look at:

JP 60-066806 A -- does it say anything about a nb-al (niobium aluminum) alloy on page 2 lower right column, page 3 upper right column, claims?

JP 01-124212 -- does it say anything about a nb-al (niobium aluminum) alloy on page 2 lower part, page 3 upper right column, claims?

If the alloy is discussed... do the references discuss "dendrite microstructures"/capacitors?

Thanks,

Eric

Eric W. Thomas

Primary Patent Examiner United States Patent & Trademark Office Jefferson 10 D 19 -- Art Unit 2831

(571) 272-1985

This message may contain information which is privileged or confidential. If you are not the named addressee of this message please destroy it without reading, using, copying or disclosing its contents to any other person.

=> d his full (FILE 'CAPLUS' ENTERED AT 15:12:09 ON 19 MAY 2006) DELETE HIS FILE 'REGISTRY' ENTERED AT 15:14:35 ON 19 MAY 2006 L1 1 SEA ABB=ON PLU=ON AL3 NB/MF L21 SEA ABB=ON PLU=ON AL NB2/MF L3 1 SEA ABB=ON PLU=ON AL NB3/MF 133569 SEA ABB=ON PLU=ON NB/ELS L4FILE 'CAPLUS' ENTERED AT 15:21:36 ON 19 MAY 2006 L5 44 SEA ABB=ON PLU=ON L1 AND L2 AND L3 AND L4 E CAPACITORS/CT E E3+ALL SET LINE 250 SET DETAIL OFF E CAPACITORS+ALL/CT SET LINE LOGIN SET DETAIL LOGIN L6 71782 SEA ABB=ON PLU=ON (CAPACITOR OR "ELECTRIC CONDENSERS" OR "CERAMIC CAPACITORS" OR "ELECTRIC CAPACITORS" (L) "CERAMIC, MULTILAYER" OR "ELECTRIC CAPACITORS" (L) "SEMICONDUCTIVE" OR "ELECTROLYTIC CAPACITORS") 1 SEA ABB=ON PLU=ON L5 AND L6 L7D IBIB ABS HITSTR FILE 'REGISTRY' ENTERED AT 15:30:37 ON 19 MAY 2006 L8313 SEA ABB=ON PLU=ON AL.NB/MF L9 49 SEA ABB=ON PLU=ON AL NB/ELF FILE 'CAPLUS' ENTERED AT 15:32:48 ON 19 MAY 2006 L10 2027 SEA ABB=ON PLU=ON L8 OR L9 L11 28 SEA ABB=ON PLU=ON L6 AND L10 L1227 SEA ABB=ON PLU=ON L11 NOT L7 D IBIB ABS HITSTR 1-27 FILE 'INSPEC, COMPENDEX' ENTERED AT 15:38:32 ON 19 MAY 2006 1343 SEA ABB=ON PLU=ON (NBAL3 OR NB2AL OR NB3AL OR NB3AL)/ET L13 L14 1 SEA ABB=ON PLU=ON L6 AND L13 D IALL L15 1465 SEA ABB=ON PLU=ON (NBAL3 OR NB2AL OR NB3AL OR NB3AL OR NBAL)/ET L16 2 SEA ABB=ON PLU=ON L6 AND L15 L17 1 SEA ABB=ON PLU=ON L16 NOT L14 D IALL FILE 'WPIX' ENTERED AT 15:44:51 ON 19 MAY 2006 L18 231 SEA ABB=ON PLU=ON NBAL3 OR NB2AL OR NB3AL OR NB3AL OR NBAL OR NEODYMIUM(W) (ALUMINUM OR ALUMINIUM) 4 SEA ABB=ON PLU=ON L18 AND L6 L19 D IFULL 1-4

EIC 2800 MARY S. MIMS 272-5928

E E2+A

FILE 'CAPLUS' ENTERED AT 15:53:23 ON 19 MAY 2006 44 SEA ABB=ON PLU=ON L5 NOT L12

E DENDRITIC/CT

		E DENDRITIC/CT
		E E2+ALL
		SET LINE 250
		SET DETAIL OFF
		E DENDRITES+ALL/CT
		SET LINE LOGIN
		SET DETAIL LOGIN
		SET LINE 250
		SET DETAIL OFF
		E MICROSTRUCTURE+ALL/CT
		SET LINE LOGIN
		SET DETAIL LOGIN
L21	18427	SEA ABB=ON PLU=ON DENDRITES OR CRYSTAL(W)NEDDLE OR DENDRIT?(4
		W) ((MICROSTRUCTURE OR "POLE FIGURES" OR "TEXTURE" OR "AMORPHOUS
		STATE" OR "AMORPHOUS STRUCTURE" OR "GLASS STRUCTURE" OR
		"GLASSY STATE" OR "VITREOUS STATE" OR "AUSTENITIC STRUCTURE"
		OR "AUSTENITE"))
L22	1	SEA ABB=ON PLU=ON L20 AND L21
		D IBIB ABS HITSTR
L23	383434	SEA ABB=ON PLU=ON DENDRITES OR CRYSTAL(W)NEEDLE OR ((MICROSTR
		UCTURE OR "POLE FIGURES" OR "TEXTURE" OR "AMORPHOUS STATE" OR
		"AMORPHOUS STRUCTURE" OR "GLASS STRUCTURE" OR "GLASSY STATE"
		OR "VITREOUS STATE" OR "AUSTENITIC STRUCTURE" OR "AUSTENITE"))
L24	8	SEA ABB=ON PLU=ON L20 AND L23
L25	7	SEA ABB=ON PLU=ON L24 NOT L22
		D IBIB ABS HITSTR 1-7

L12 ANSWER 8 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2004:78331 CAPLUS

DOCUMENT NUMBER: 140:137728

TITLE: Electrolytic capacitor and a fabrication

method therefor

INVENTOR(S): Yano, Mutsumi; Takatani, Kazuhiro; Kimoto, Mamoru

PATENT ASSIGNEE(S): Sanyo Electric Co., Ltd., Japan SOURCE: U.S. Pat. Appl. Publ., 12 pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.		DATE
				-	
US 2004016978	A1	20040129	US 2003-611969		20030703
US 6876083	B2	20050405			
JP 2004349658	A2	20041209	JP 2003-175955		20030620
TW 225656	B1	20041221	TW 2003-92118048		20030702
CN 1474422	Α	20040211	CN 2003-133189		20030725
PRIORITY APPLN. INFO.:			JP 2002-217482	Α	20020726
			JP 2003-80792	Α	20030324

AB An electrolytic capacitor of the invention includes one type of electrode selected from a group consisting of an electrode of at least one type of alloy selected from a group consisting of niobium alloy, titanium alloy, and tungsten alloy, an electrode of mixed sinter of niobium and aluminum, or a fluorine-doped electrode of niobium or niobium alloy and on a surface of the each electrodes a dielec. layer is formed by anodizing the electrode.

IT 39396-75-3

RL: DEV (Device component use); USES (Uses)
 (design of electrolytic capacitor and a method of its
fabrication)

RN 39396-75-3 CAPLUS

CN Aluminum alloy, nonbase, Al, Nb (9CI) (CA INDEX NAME)

Component Component
Registry Number
Al 7429-90-5

7440-03-1

REFERENCE COUNT: 10 THERE ARE 10 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L12 ANSWER 9 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2003:890033 CAPLUS

DOCUMENT NUMBER: 139:384501

TITLE: Manufacture of Al-Nb alloy foil for electrolytic

capacitor

INVENTOR(S): Kawabata, Hiroyuki; Tsukuda, Ichizo

PATENT ASSIGNEE(S): Showa Denko K. K., Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 12 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 2003321762	A2	20031114	JP 2002-125637	20020426
PRIORITY APPLN. INFO.:			JP 2002-125637	20020426

AB An Al-Nb alloy foil (thickness: 20-500 μ m) is manufactured by rapid solidification of molten alloy on a cooling roll under a N-containing atmospheric As

a result, the Al-Nb intermetallic compound particles on the foil are nitrided to form a surface film of Al-Nb-N. The obtained foil is suitable for electrolytic capacitor application with reduced current leakage.

IT 39309-34-7 81318-84-5 107240-82-4

111235-60-0, Aluminum 5, niobium 95 121165-63-7,

Aluminum 93, niobium 7 121165-65-9, Aluminum 88, niobium 12

178275-74-6, Aluminum 15, niobium 85

RL: NUU (Other use, unclassified); USES (Uses)

(manufacture of Al-Nb alloy foil for electrolytic capacitor)

RN 39309-34-7 CAPLUS

CN Aluminum alloy, base, Al 97,Nb 3 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
======+=	=========	+=========
Al	97	7429-90-5
Nb	3	7440-03-1

RN 81318-84-5 CAPLUS

CN Aluminum alloy, base, Al 95,Nb 5 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
======+=		-+==========
Al	95	7429-90-5
Nb	5	7440-03-1

RN 107240-82-4 CAPLUS

CN Aluminum alloy, base, Al 98, Nb 2 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
======+=	=========	+==========
Al	98	7429-90-5
Nb	2	7440-03-1

RN 111235-60-0 CAPLUS

CN Niobium alloy, base, Nb 95,Al 5 (9CI) (CA INDEX NAME)

RN 121165-63-7 CAPLUS

CN Aluminum alloy, base, Al 93, Nb 7 (9CI) (CA INDEX NAME)

RN 121165-65-9 CAPLUS

CN Aluminum alloy, base, Al 88, Nb 12 (9CI) (CA INDEX NAME)

RN 178275-74-6 CAPLUS

CN Niobium alloy, base, Nb 85, Al 15 (9CI) (CA INDEX NAME)

L12 ANSWER 11 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

```
ACCESSION NUMBER:
                         2002:143037 CAPLUS
DOCUMENT NUMBER:
                         136:192880
TITLE:
                         Niobium powder, sinter thereof, and capacitor
                         employing the same
INVENTOR(S):
                         Omori, Kazuhiro; Naito, Kazumi
PATENT ASSIGNEE(S):
                         Showa Denko K.K., Japan
SOURCE:
                         PCT Int. Appl., 115 pp.
                         CODEN: PIXXD2
DOCUMENT TYPE:
                         Patent
LANGUAGE:
                         Japanese
FAMILY ACC. NUM. COUNT:
PATENT INFORMATION:
     PATENT NO.
                         KIND
                                DATE
                                           APPLICATION NO.
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                                 -----
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                         ----
     WO 2002015208
                                           WO 2001-JP6857
                          A1
                                20020221
                                                                    20010809
         W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN,
             CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD, GE, GH,
             GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR,
             LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NO, NZ, PL, PT,
             RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, TZ, UA, UG, UZ,
             VN, YU, ZA, ZW
         RW: GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZW, AT, BE, CH, CY,
             DE, DK, ES, FI, FR, GB, GR, IE; IT, LU, MC, NL, PT, SE, TR, BF,
             BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG
     CA 2418865
                          AA
                                20020221
                                          CA 2001-2418865
                                                                    20010809
     AU 2001077734
                          A5
                                20020225
                                            AU 2001-77734
                                                                    20010809
     EP 1324359
                          A1
                                20030702
                                            EP 2001-955623
                                                                    20010809
             AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT,
             IE, SI, LT, LV, FI, RO, MK, CY, AL, TR
     BR 2001013215
                                            BR 2001-13215
                         Α
                                20050201
                                                                    20010809
     RU 2267182
                          C2
                                             RU 2003-105884
                                20051227
                                                                    20010809
     US 2002064476
                         A1
                                20020530
                                             US 2001-925686
                                                                    20010810
     US 6652619
                         B2
                                20031125
     US 2003205106
                         A1
                                20031106
                                             US 2003-341229
                                                                    20030113
PRIORITY APPLN. INFO.:
                                             JP 2000-243486
                                                                 A 20000810
                                                                 A 20001219
                                             JP 2000-384720
                                             JP 2001-65852
                                                                 A 20010309
                                             JP 2001-174018
                                                                 Α
                                                                    20010608
                                             US 2000-240828P
                                                                 P
                                                                    20001017
                                             US 2001-269855P
                                                                 P
                                                                    20010221
                                             US 2001-275467P
                                                                 P
                                                                    20010314
                                             US 2001-297441P
                                                                 P
                                                                    20010613
                                             WO 2001-JP6857
                                                                 W
                                                                    20010809
                                             US 2001-925686
                                                                 A1 20010810
     A Nb powder containing at least one element selected from the group consisting
ΑŖ
     of Cr, Mo, W, B, Al, Ga, In, Tl, Ce, Nd, Ti, Re, Ru, Rh, Pd, Ag, Zn, Si,
     Ge, Sn, P, As, Bi, Rb, Cs, Mg, Sr, Ba, Sc, Y, La, Pr, Sm, Eu, Gd, Tb, Dy, Ho, Er, Tm, Yb, Lu, Hf, V, Os, Ir, Pt, Au, Cd, Ag, lead, Se, and Te; a
     sinter of the Nb powder; and a capacitor which comprises the
     sinter serving as one electrode, a dielec. formed on the sinter, and the
     other electrode disposed on the dielec.
IT
     57720-22-6
     RL: DEV (Device component use); PEP (Physical, engineering or chemical
     process); PROC (Process); USES (Uses)
        (sintering niobium alloy powders in manufacture of capacitors)
RN
     57720-22-6 CAPLUS
```

CN Niobium alloy, base, Nb 100, Al 0.3 (9CI) (CA INDEX NAME)

Component	Component Percent	Component Registry Number
======+=	=========	+=========
Nb	100	7440-03-1
Al	0.3	7429-90-5

REFERENCE COUNT:

THERE ARE 23 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L12 ANSWER 13 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2000:505697 CAPLUS

DOCUMENT NUMBER: 133:180971

TITLE: Electro-discharge consolidation (EDC) applied to

nanocrystalline and RSP/MA powders

AUTHOR(S): Okazaki, K.

CORPORATE SOURCE: Department of Chemical and Materials Engineering,

University of Kentucky, Lexington, KY, 40506-0046, USA

SOURCE: Materials Science & Engineering, A: Structural

Materials: Properties, Microstructure and Processing

(2000), A287(2), 189-197

CODEN: MSAPE3; ISSN: 0921-5093

PUBLISHER: Elsevier Science S.A.

DOCUMENT TYPE: Journal LANGUAGE: English

AB EDC was applied to consolidate nanocryst. intermetallic powders and rapid solidification processing (RSP) Al alloy powders. Because EDC employs a high-voltage, high-d. current pulse discharged from a capacitor bank to powders under external pressure, one can take advantage of the basic characteristics of EDC to preserve the microstructure inherent in the starting powder, remove oxide films on the prior powder particle surface to enhance the bonding, densify to the bulk and thereby improve the mech. properties. Mech. alloyed Nb-23 atomic% Al was consolidated to a d. of 99% theor., and the nanocryst. state (<35 nm grain size) was preserved. Because of such a small grain size, the EDC consolidates exhibit a neg. Hall-Petch relation. Another example is presented for RSP and MA powders of an Al alloy, in which the magnitude of ductilities exhibited by EDC bulks clearly indicates that the oxide film on the powder particle surface was completely removed.

IT 88872-57-5P, Aluminum 23, niobium 77 (atomic)

RL: PNU (Preparation, unclassified); PREP (Preparation)

(electro-discharge consolidation applied to nanocryst. and rapid

solidification processing/mech. alloyed powders)

RN 88872-57-5 CAPLUS

CN Niobium alloy, base, Nb 92, Al 8 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
======+=		+==========
Nb	92	7440-03-1
Al	8	7429-90-5

REFERENCE COUNT: 19 THERE ARE 19 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L12 ANSWER 14 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1998:121496 CAPLUS

DOCUMENT NUMBER: 128:207571

TITLE: Electro-discharge consolidation of nanocrystalline

Nb-Al powders prepared by mechanical alloying

AUTHOR(S): Okazaki, Kenji

CORPORATE SOURCE: Department of Chemical and Materials Engineering,

University of Kentucky, Lexington, KY, 40506-0046, USA

SOURCE: THERMEC '97, International Conference on

Thermomechanical Processing of Steels and Other

Materials, 2nd, Wollongong, Australia, July 7-11, 1997 (1997), Volume 2, 1379-1385. Editor(s): Chandra, T.; Sakai, T. Minerals, Metals & Materials Society:

Warrendale, Pa. CODEN: 65RAAQ Conference

DOCUMENT TYPE: LANGUAGE:

Conference English

AB A Nb-23 atomic% Al alloy was prepared by mech. alloying. Careful deconvolution of XRD revealed that the mech. alloyed powder was a mixture of multi-phase nanocryst. (5-9 nm) Nb3Al, Nb2Al, Nb and Al. The powder under external pressure was subjected to a high-voltage, high-d. current pulse from a capacitor bank to produce a consolidated body having a relative d. of ≤97.5% theor. The consolidated body was still a mixture of two nanocryst. (13-33 nm) Nb3Al and Nb2Al phases. Compression tests at ambient temperature resulted in a yield strength of 826 MPa and strain to fracture of 1.9%. An increase in temperature to 1233 K resulted in a decrease in yield strength to 500 MPa but an increase in ductility to >40%. The strain rate sensitivity exponent was >0.4 and suggested that the high-temperature deformation is controlled by grain rotation or grain-boundary sliding.

IT 12003-74-6P 12003-75-7P

RL: PNU (Preparation, unclassified); PREP (Preparation) (electro-discharge consolidation of mech.-alloyed nanocryst. Nb-Al powders containing phase of)

RN 12003-74-6 CAPLUS

CN Aluminum, compd. with niobium (1:2) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
Nb	2	7440-03-1
Al	1	7429-90-5

RN 12003-75-7 CAPLUS

CN Aluminum, compd. with niobium (1:3) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
Nb	3	7440-03-1
Al	1	7429-90-5

IT 88872-57-5, Aluminum 23, niobium 77 (atomic)

RL: PEP (Physical, engineering or chemical process); PRP (Properties); PROC (Process)

(electro-discharge consolidation of nanocryst. Nb-Al powders prepared by mech. alloying)

RN 88872-57-5 CAPLUS

CN Niobium alloy, base, Nb 92, Al 8 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
======+=	.========	-+==========
Nb	92	7440-03-1
Al	8	7429-90-5

REFERENCE COUNT:

14 THERE ARE 14 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L12 ANSWER 15 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1995:249068 CAPLUS

DOCUMENT NUMBER: 122:69985

TITLE: Manufacture of aluminum electrode material for

electrolytic capacitor

INVENTOR(S): Kuroki, Tosha; Mizunuma, Susumu; Fukutani, Kazuhiko

PATENT ASSIGNEE(S): Shinnippon Seitetsu KK, Japan SOURCE: Jpn. Kokai Tokkyo Koho, 4 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 06264201	A2	19940920	JP 1993-54241	19930315
PRIORITY APPLN. INFO.:			JP 1993-54241	19930315

AB The title method involves the following steps; laminating rapidly solidified Al alloy foils containing 1-25 atomic% Zr on the both sides of an Al foil, heating at 250-400°, one-step or multistep clad rolling with rolling draft 3-90%, and heating at 250-400°. The material showed high capacitance.

IT 106933-67-9

RL: DEV (Device component use); PEP (Physical, engineering or chemical process); PROC (Process); USES (Uses)

(elec. insulator; hot cladding of aluminum alloy elec. insulator and aluminum for manufacture of electrode material of electrolytic capacitor)

RN 106933-67-9 CAPLUS

CN Aluminum alloy, base, Al 93, Nb 6.6 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
=======+=	=========	+=========
Al	93	7429-90-5
Nb	6.6	7440-03-1

L12 ANSWER 16 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1994:619596 CAPLUS

DOCUMENT NUMBER: 121:219596

TITLE: Chip-type solid electrolytic

capacitors with low loss

INVENTOR(S): Mochizuki, Takashi PATENT ASSIGNEE(S): Nichikon Kk, Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 4 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 06120088	A2	19940428	JP 1992-286586	19920930
JP 3199871	B2	20010820		

PRIORITY APPLN. INFO.: JP 1992-286586 19920930

The capacitors contain two solid electrolytic capacitor devices comprising Al or Al-based alloy electrodes, which are etched to increase their effective areas, successively coated with anode oxide coating layers, solid electrolytic layers, and cathode conductive layers, in which anode leads are from opposite directions of the devices and cathode leads are from junctions of the devices at 90° towards the anode leads.

IT 39396-75-3

RL: USES (Uses)

(chip-type solid electrolytic capacitor electrodes containing)

RN 39396-75-3 CAPLUS

CN Aluminum alloy, nonbase, Al, Nb (9CI) (CA INDEX NAME)

L12 ANSWER 18 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1994:151577 CAPLUS

DOCUMENT NUMBER: 120:151577

TITLE: Solid electrolytic capacitor and its

manufacture

INVENTOR(S): Saiki, Yoshihiko

PATENT ASSIGNEE(S): Nippon Electric Co, Japan SOURCE: Jpn. Kokai Tokkyo Koho, 3 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
	-			
JP 05243101	A2	19930921	JP 1992-73048	19920226
PRIORITY APPLN. INFO.:			JP 1992-73048	19920226

AB The capacitor consists of an anode, obtained by press shaping powdered amorphous metals and sintering, coated with a dielec. layer, a solid electrolyte layer, a cathode metal layer, and an anode lead. The capacitor is manufactured by mech. milling to form powdered amorphous alloys, press shaping, sintering at lower temperature than crystallization temperature of the

alloys in vacuum to form an anode, and forming a dielec. film, a solid electrolyte layer, and a cathode metal layer. The **capacitor** showed good insulation withstand voltage.

IT 39396-75-3

RL: USES (Uses)

(amorphous, sintering of, electrolytic capacitor anode from, with good insulation withstand voltage)

RN 39396-75-3 CAPLUS

CN Aluminum alloy, nonbase, Al, Nb (9CI) (CA INDEX NAME)

Component Component
Registry Number
Al 7429-90-5

Al 7429-90-5 Nb 7440-03-1 L12 ANSWER 19 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1992:431549 CAPLUS

DOCUMENT NUMBER: 117:31549

TITLE: Nano-crystalline consolidation of MA powders by EDC

AUTHOR(S): Kim, D. K.; Okazaki, K.

CORPORATE SOURCE: Univ. Kentucky, Lexington, KY, 40506-0046, USA

SOURCE: Materials Science Forum (1992), 88-90 (Mech. Alloying),

553-60

CODEN: MSFOEP; ISSN: 0255-5476

DOCUMENT TYPE: Journal LANGUAGE: English

AΒ Appender mixture of elemental Nb (54.5 weight%) and Al (45.5 weight%) to form NbAl3 was mech. alloyed (MA) in an Ar-filled jar mill for 25-500 h. The elemental particulate size measured from the line-broadening decreases with increasing the MA time of up to 200 h from 40 to 4 nm, while sizes are 2-7 nm. DSC studies were carried out at several heating rates to thermally analyze both the endothermic and exothermic reactions. The exothermic reaction is due to the devitrification of the amorphous which varies with the MA time, while the endothermic reaction is due to the formation of NbAl3 from both Nb2Al and a mixture recrystd. from the amorphous, exhibiting a constant activation energy of 45 kcal/mol regardless of the MA time. The energies for devitrification decreases from 42 to 37 kcal/mol with an increase in the MA time from 100 to 500 h. A high-voltage, high-d. elec. current pulse was subjected in air from-a capacitor bank of 500 or 720 µF to the powders mech. alloyed for 300 or 500 h under 207 to 483 MPa, instantaneously producing a solid compact of mostly NbAl3. The resultant grain size of elec.-dischargecompacted (EDC) compacts produced at 22-100 nm. A Hall-Petch relation exists between microhardness (10,000-12,000 MPa) and square root of grain size up to .apprx.60 nm. When grain sizes are further reduced from 60 nm, however, softening actually occurs with a decrease in grain size. 7000 MPa was obtained for grain sizes of ≤40 nm. Annealing of compacts having smaller grain sizes than 50 nm at 1273 K for 4 h increases their grain size and hardness which are in the pos. Hall-Petch relation side. This fact indicates that ductile intermetallic compds. made by EDC having very small grain sizes can be then strengthened by annealing to increase their grain sizes beyond 60 nm.

IT 118435-58-8

RL: USES (Uses)

(consolidation of mech. alloyed, by elec. discharge)

RN 118435-58-8 CAPLUS

CN Niobium alloy, base, Nb 54,Al 46 (9CI) (CA INDEX NAME)

Component	Component Percent	Component Registry Number
	=========	+=========
Nb	54	7440-03-1
Al	46	7429-90-5

IT 12004-70-5P

RL: PREP (Preparation)

(preparation of, by mech. alloying and elec.-discharge consolidation)

pot for

RN 12004-70-5 CAPLUS

CN Aluminum, compd. with niobium (3:1) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component
		Registry Number
	+======================================	

EIC 2800 MARY S. MIMS 272-5928

, ,

Nb Al 1 3 7440-03-1 7429-90-5

EIC 2800 MARY S. MIMS 272-5928 L12 ANSWER 20 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1992:203243 CAPLUS

DOCUMENT NUMBER: 116:203243

TITLE: Electrolytic capacitors produced

from deformation-processed two-phase alloys

AUTHOR(S): Gibson, E. D.; Verhoeven, J. D.

CORPORATE SOURCE: Ames Lab., Iowa State Univ., Ames, IA, 50011, USA

SOURCE: Journal of Materials Science: Materials in

Electronics (1991), 2(4), 236-43 CODEN: JSMEEV; ISSN: 0957-4522

DOCUMENT TYPE: Journal LANGUAGE: English

Arc cast Cu-Ta and powder processed Al-Ta and Al-Nb composite alloys were examined as potential materials for making electrolytic capacitors. These two phase alloys can be severely cold-worked, deformation-processed, to produce Ta surface areas considerably larger than those possible with the powder processing used in current Ta capacitors. The three alloys were deformation-processed into sheet and rod form and then processed through anodization electrolyte formation and cathode fabrication steps to make prototype capacitors. The capacitors were tested for capacitance, effective series resistance and leakage. The figure of merit, CVq-1, (capacitance + voltage per g) values obtained closely approached those of currently manufactured capacitors but d.c. leakage values were unacceptably high using a solid electrolyte. To realize the full potential of this new method for fabricating Al-Ta capacitors further research is required to improve the deformation of the Ta powders and to find methods of anodization and solid-state electrolyte formation capable of maintaining oxide film integrity.

IT 96340-68-0

RL: RCT (Reactant); RACT (Reactant or reagent)
 (anodization of, in ammonium citrate or phosphoric acid for
 electrolytic capacitors)

RN 96340-68-0 CAPLUS

CN Niobium alloy, base, Nb 76, Al 24 (9CI) (CA INDEX NAME)

Component	Component
Percent	Registry Number
=========	:+==========
76	7440-03-1
24	7429-90-5
	Percent ====================================

IT 80207-84-7

RL: RCT (Reactant); RACT (Reactant or reagent)
 (anodization of, in phosphoric acid for electrolytic
 capacitors)

RN 80207-84-7 CAPLUS

CN Niobium alloy, base, Nb 91, Al 9.3 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
======+=	==========	+=========
Nb	91	7440-03-1
Al	9.3	7429-90-5

L12 ANSWER 21 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1992:185986 CAPLUS

DOCUMENT NUMBER: 116:185986

TITLE: Contacts to semiconductors having zero resistance INVENTOR(S): Jackson, Thomas Nelson; Kleinsasser, Alan Willis

PATENT ASSIGNEE(S): International Business Machines Corp., USA

SOURCE: Eur. Pat. Appl., 7 pp.

CODEN: EPXXDW

DOCUMENT TYPE: Patent LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
EP 460356	A2	19911211	EP 1991-102860	19910227
EP 460356	A3	19921104		
R: DE, FR, GB				
JP 07074403	A2	19950317	JP 1991-103714	19910314
PRIORITY APPLN. INFO.:			US 1990-534078 A	19900606

AB A FET includes a source electrode, a drain electrode, and a gate electrode elec. coupled to a body of semiconductor material. At least the drain electrode and the source electrode are each comprised of a material having superconducting properties below a predetd. temperature The source electrode and the drain electrode are each disposed relative to the body of semiconductor material for inducing, via the proximity effect, a superconducting state into adjacent material of the body of semiconductor material. As a result, a parasitic elec. resistance associated with the source electrode and the drain electrode is substantially or entirely eliminated. The source and drain electrodes may be comprised of

low-temperature

or of high temperature superconducting material.

IT 12003-75-7

RL: TEM (Technical or engineered material use); USES (Uses) (superconductive contact containing, for semiconductor device)

RN 12003-75-7 CAPLUS

CN Aluminum, compd. with niobium (1:3) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
Nb		7440-03-1
Al	1	7429-90-5

L12 ANSWER 22 OF 27 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1989:623755 CAPLUS

DOCUMENT NUMBER: 111:223755

TITLE: Aluminum alloy electrodes for electrolytic

capacitors

INVENTOR(S): Mochizuki, Takashi; Takenoiri, Kazuo; Sekiquchi,

Shoichi; Endo, Michio; Sukai, Tetsuya

PATENT ASSIGNEE(S): Nichicon Corp., Japan; Nippon Steel Corp.

SOURCE: Jpn. Kokai Tokkyo Koho, 5 pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 01124212	A2	19890517	JP 1987-282742	19871109
JP 08028312	B4	19960321		
ODITY ADDIN INTO .			TD 1007 202742	10071100

PRIORITY APPLN. INFO.: JP 1987-282742 19871109

AB The title electrodes are Al alloys containing fine dispersions of intermetallic compds. of Al with Ti, Ta, Zr, Hf, and/or Nb.

Capacitors having large electrostatic capacitance are prepared

Thus, a foil prepared from Al-6 atomic% Zr alloy by rapid quenching was etched in aqueous HCl with d.c. application and then conversion treated to give a capacitor electrode.

IT 106933-67-9

RL: USES (Uses)

(electrode, capacitor)

RN 106933-67-9 CAPLUS

CN Aluminum alloy, base, Al 93, Nb 6.6 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
=======+=	=========	+===========
Al	93	7429-90-5
Nb	6.6	7440-03-1

AUTHOR:

(C) 2006 IET on STN ANSWER 1 OF 1 INSPEC T.14 1998:6061212 INSPEC ACCESSION NUMBER:

DOCUMENT NUMBER: A1998-23-8120G-007

Electro-discharge consolidation of nanocrystalline TITLE:

Nb-Al powders prepared by mechanical alloying Okazaki, K. (Dept. of Chem. & Mater. Eng., Kentucky

Univ., Lexington, KY, USA)

SOURCE: THERMEC'97. International Conference on

> Thermomechanical Processing of Steels and Other Materials, vol.2, 1997, p. 1379-87 vol.2 of 2 vol.

(xxxvi+xxviii+2397) pp., 13 refs. Editor(s): Chandra, T.; Sakai, T.

ISBN: 0 87339 377 5

Published by: TMS, Warrendale, PA, USA

Conference: Proceedings of International Conference on

Materials, Processing at High Temperature

(THERMEC'97), Wollongong, NSW, Australia, 7-11 July

Sponsor(s): U.S. Air Force Office for Sci. Res

DOCUMENT TYPE: Conference; Conference Article

TREATMENT CODE: Experimental COUNTRY: United States

LANGUAGE: English

ABSTRACT: A 77 atomic%Nb-23 atomic%Al alloy was prepared by mechanical

> alloying. Careful deconvolution of XRD revealed that the MA powder was a mixture of multi-phase

nanocrystalline (5-9 nm) Nb3Al, Nb2Al, Nb and Al. This multi-phase powder under external pressure was subjected to a high-voltage, high-density current

pulse from a capacitor bank to produce a

consolidated bulk having a relative density of up to 97.5%. The consolidated bulk was still a mixture of two nanocrystalline (13-33 nm) Nb3Al and Nb2Al phases. Compression tests at ambient temperature exhibit the yield strength of 826 MPa and strain to fracture of 1.9%. An increase in temperature to 1233 K results in

a decrease the yield strength to 500 MPa but an increase in ductility to more than 40%. The strain

rate sensitivity m in Λlnσ/Δln.epsi

lon. was found to be greater than 0.4, suggesting that high temperature deformation may be controlled by

grain rotation or grain boundary sliding

CLASSIFICATION CODE: A8120G Preparation of metals and alloys (compacts, pseudoalloys); A6480G Microstructure; A8120E Powder

techniques, compaction and sintering; A6220F Deformation and plasticity; A8140L Deformation, plasticity and creep; A6170L Slip, creep, internal friction and other indirect evidence of dislocations;

A6220M Fatigue, brittleness, fracture, and cracks;

A8140N Fatigue, embrittlement, and fracture CONTROLLED TERM:

aluminium alloys; discharges (electric); ductility;

fracture; mechanical alloying; nanostructured materials; niobium alloys; powder metallurgy; powders;

slip; X-ray diffraction; yield strength

SUPPLEMENTARY TERM: electro-discharge consolidation; nanocrystalline Nb-Al

> powders; mechanical alloying; XRD; multi-phase nanocrystalline Nb3Al; Nb2Al; multi-phase powder;

EIC 2800

MARY S. MIMS 272-5928 CHEMICAL INDEXING:

PHYSICAL PROPERTIES: ELEMENT TERMS:

high-voltage high-density current pulse; capacitor bank; consolidated bulk; compression tests; yield strength; ductility; strain rate sensitivity; high temperature deformation; grain boundary sliding; grain rotation; 1233 K; Nb3Al; Nb-Al Nb3Al bin, Nb3 bin, Al bin, Nb bin; Nb2Al bin, Nb2 bin, Al bin, Nb bin; NbAl bin, Al bin, Nb bin temperature 1.233E+03 K Al*Nb; Al sy 2; sy 2; Nb sy 2; Nb-Al; Nb3Al; Nb cp; cp; Al cp; Al; Nb; Nb2Al

L19 ANSWER 1 OF 4 WPIX COPYRIGHT 2006 THE THOMSON CORP on STN

ACCESSION NUMBER: 2005-201631 [21] WPIX

CROSS REFERENCE: 2004-498606 [47] DOC. NO. NON-CPI: N2005-165958 DOC. NO. CPI: C2005-064276

TITLE: Fabrication of TFT-LCD comprises forming first metal

layer, patterning first metal layer, forming

gate-insulating layer, and forming semiconductor layer on

the insulating layer.

DERWENT CLASS: L03 U11 U12 U14

INVENTOR(S):

CHEN, M

1

PATENT ASSIGNEE(S):

(CHEN-I) CHEN M

COUNTRY COUNT:

PATENT INFORMATION:

APPLICATION DETAILS:

PATENT NO	KIND	APPLICATION	DATE
US 2005037528		US 2003-647885 US 2004-947747	20030825 20040923

PRIORITY APPLN. INFO: TW 2002-137146 20021224

INT. PATENT CLASSIF.:

MAIN: H01L021-00 SECONDARY: H01L021-84

BASIC ABSTRACT:

US2005037528 A UPAB: 20050401

NOVELTY - Thin film transistor-liquid crystal display (TFT-LCD) is fabricated by forming first metal layer on a transparent substrate (100), patterning the first metal layer to form at least two adjacent gate electrodes, forming a gate insulating layer on the gate electrodes, and forming a semiconductor layer on the insulating layer.

DETAILED DESCRIPTION - Fabrication of thin film transistor-liquid crystal display comprises:

- (a) forming first metal layer on a transparent substrate:
- (b) patterning the first metal layer to form at least two adjacent gate electrodes;
 - (c) forming a gate insulating layer on the gate electrodes;
 - (d) forming a semiconductor layer on the insulating layer;
 - (e) depositing a second metal layer on the transparent substrate;
- (f) patterning the second metal layer to form a source/drain electrode layer (330);
 - (g) depositing an insulating layer on the transparent substrate;
- (h) defining a contact hole (340) via the insulating layer, source/drain electrode layer, and gate insulating layer, and exposing a part of the surface of transparent substrate between the adjacent gate electrodes;
- (i) depositing a transparent conductive layer on the transparent substrate; and
- (j) forming a light-shielding matrix (360) directly above the contact hole.

USE - For fabricating a TFT-LCD.

ADVANTAGE - Reduces the number of required photolithography steps in production of a TFT-LCD, shortens manufacturing time, increases throughput, and lowers the costs. The design in the formation of the gate electrodes on sides of the contact hole prevents over-etching of the contact holes, thus protecting the gate electrodes from short circuit. The light-shielding matrix directly above the contact hole prevents light leakage around the contact hole.

DESCRIPTION OF DRAWING(S) - The figure is a top view of a TFT-LCD.

Transparent substrate 100

Gate line area 310

Source/drain electrode layer 330

Contact hole 340

Indium tin oxide layer 350
Light-shielding matrix 360
Capacitor line 370

Gate line 380

Dwg.3/4

TECHNOLOGY FOCUS:

US 2005037528 A1UPTX: 20050401

TECHNOLOGY FOCUS - INORGANIC CHEMISTRY - Preferred Process: The fabrication of TFT-LCD further includes providing a color filter at a predetermined distance above the transparent substrate. The light-shielding matrix directly above the contact hole is disposed on the color filter. The gate electrodes are separated from the contact hole. Preferred Component: The gate electrode is a molybdenum-aluminum-neodymium electrode. The source/drain electrode layer is aluminum aluminum-niobium, aluminum-neodymium, aluminum, or

aluminum-silicon-copper layer. The gate-insulating layer is an oxide layer formed through chemical vapor deposition (CVD). The insulating layer is an oxide or nitride layer formed through CVD.

TECHNOLOGY FOCUS - ORGANIC CHEMISTRY - Preferred Process: The fabrication of TFT-LCD further includes providing a color filter at a predetermined distance above the transparent substrate. The light-shielding matrix directly above the contact hole is disposed on the color filter. The gate electrodes are separated from the contact hole. Preferred Component: The gate electrode is a molybdenum-aluminum-neodymium electrode. The source/drain electrode layer is aluminum aluminum-niobium, aluminum-neodymium, aluminum-titanium, or aluminum-silicon-copper

layer. The gate-insulating layer is an oxide layer formed through chemical vapor deposition (CVD). The insulating layer is an oxide or nitride layer formed through CVD.

FILE SEGMENT: CPI EPI FIELD AVAILABILITY: AB; GI

MANUAL CODES: CPI: L03-G05B6; L04-C06; L04-C11C1; L04-C12; L04-E01E

EPI: U11-C18A1; U12-B03A; U14-K01A1J

L19 ANSWER 4 OF 4 WPIX COPYRIGHT 2006 THE THOMSON CORP on STN

ACCESSION NUMBER: 2003-329640 [31] WPIX

2

DOC. NO. NON-CPI: N2003-263756 DOC. NO. CPI: C2003-085674

TITLE: Dielectric ceramic composition for multilayered components, consists mixed oxide of lanthanum,

neodymium, aluminum or yttrium, and

neodymium or tantalum in specific mole fractions..

DERWENT CLASS: L03 V01 X12

INVENTOR(S): HONG, K S; KIM, D W; KIM, J Y; KWON, D G; PARK, J S;

HONG, G S; KIM, D; KIM, J; KWON, D; PARK, J

PATENT ASSIGNEE(S): (HONG-I) HONG K S; (HONG-I) HONG G S; (KIMD-I) KIM D;

(KIMJ-I) KIM J; (KWON-I) KWON D; (PARK-I) PARK J;

(HONG-I) HONG K

COUNTRY COUNT:

PATENT INFORMATION:

PATENT NO	KIND DATE	WEEK LA	PG MAIN IPC
US 2003004051	A1 200301	.02 (200331)*	8 C04B035-495
KR 2002088527	A 200211	29 (200331)	C04B035-50
US 6620750	B2 200309	16 (200362)	C04B035-495
KR 426219	B 200404	06 (200451)	H01G004-12

APPLICATION DETAILS:

PATENT NO	KIND	APPLICATION	DATE
US 2003004051	A1	US 2001-945717	20010905
KR 2002088527	A	KR 2001-27158	20010518
US 6620750	B2	US 2001-945717	20010905
KR 426219	В	KR 2001-27158	20010518

FILING DETAILS:

PATENT NO	KII	ND		I	PATENT	NO
		- 				
KR 426219	В	Previous I	Publ.	KR	200208	8527

PRIORITY APPLN. INFO: KR 2001-27158 20010518

INT. PATENT CLASSIF.:

MAIN: C04B035-495; C04B035-50; H01G004-12

SECONDARY: C04B035-505

BASIC ABSTRACT:

US2003004051 A UPAB: 20030516

NOVELTY - Dielectric ceramic composition comprises oxide(s) chosen from lanthanum trioxide, neodymium trioxide, alumina and yttrium trioxide and oxides(s) chosen from neodymium trioxide and tantalum oxide, in a molar ratio of 1:1. The ceramic composition comprises mixed oxide of lanthanum, neodymium, aluminum or yttrium, and neodymium or tantalum in specific mole fractions.

DETAILED DESCRIPTION - The dielectric ceramic composition comprises oxide(s) chosen from lanthanum trioxide, neodymium trioxide, alumina and yttrium trioxide and oxide(s) chosen from neodymium trioxide and tantalum oxide, in a molar ratio of 1:1. The dielectric composition is of formula: A'x Al-x B'y Bl-y O4, where A' and A are lanthanum, neodymium, yttrium or aluminum, B' and B are neodymium or tantalum, x and y are mole fractions, and x is 0-1 and y is 0-1. An INDEPENDENT CLAIM is included for method for

manufacturing multilayered components.

USE - For manufacture of multilayered components (claimed) such as microwave oscillator, chip LC filters, chip duplexers, dielectric filter of personal communication service (PCS), temperature stable capacitors substrates and planar antenna and for fabrication of practical lamination portions.

ADVANTAGE - The dielectric ceramic composition has excellent temperature stability, low temperature sintering properties and high dielectric quality factor at low dielectric bonds. The dielectric ceramic composition is suitable for high frequency bonds such as microwave and millimetric wave.

Dwg.0/0

FILE SEGMENT: CPI EPI

FIELD AVAILABILITY: AB

MANUAL CODES: CPI: L03-B03E; L03-D01; L03-D04D

EPI: V01-B03A1; V01-B03C3A; X12-E01A

L25 ANSWER 6 OF 7 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 1994:635799 CAPLUS

DOCUMENT NUMBER: 121:235799

TITLE: Synthesis of intermetallics by mechanical alloying AUTHOR(S): Suryanarayana, C.; Froes, F. H.; Mukhopadhyay, D. K.;

Cizmich, G.; Chen, G. H.; Peng, Z.; Mishurda, J.

CORPORATE SOURCE: Inst. Mater. Adv. Process., Univ. Idaho, Moscow, ID,

83844-3026, USA

SOURCE: Process Fabr. Adv. Mater. III, Proc. Symp., 3rd (1994)

, Meeting Date 1993, 567-84. Editor(s): Ravi, V. A.; Srivatsan, T. S.; Morre, J. J. Miner. Met. Mater.

Soc.: Warredale, Pa.

CODEN: 60MIAQ

DOCUMENT TYPE: LANGUAGE: Conference English

AB Mech. alloying is a solid-state powder processing technique to synthesize a variety of alloy phases including supersatd. solid solns., intermetallic compds., and amorphous phases. The application of mech. alloying to the synthesis of intermetallics can overcome the difficulties of mixing two metals with significantly different m.ps., narrow homogeneity ranges of some intermetallics, and the high reactivities of some metals. The paper describes the synthesis of intermetallics in the Ti-Al, Fe-Al, and Nb-Al systems with an ultrafine microstructure. HIP consolidation of some of these materials has demonstrated that they retain the nanostructures and possess high hardness and strength.

IT 12003-74-6P, AlNb2 12003-75-7P, AlNb3

12004-70-5P, Al3Nb

RL: SPN (Synthetic preparation); PREP (Preparation)

(mech. alloying synthesis of)

RN 12003-74-6 CAPLUS

CN Aluminum, compd. with niobium (1:2) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component
=======================================	 +====================================	Registry Number
Nb	2	7440-03-1
Al	1	7429-90-5

RN 12003-75-7 CAPLUS

CN Aluminum, compd. with niobium (1:3) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
=======================================		+========
Nb	3	7440-03-1
Al	1	7429-90-5

RN 12004-70-5 CAPLUS

CN Aluminum, compd. with niobium (3:1) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
Nb Al	1	7440-03-1 7429-90-5

IT 51602-53-0 60817-72-3, Aluminum 25, niobium 75 (atomic) 60817-74-5, Aluminum 30, niobium 70 (atomic) 78337-79-8,

EIC 2800 MARY S. MIMS 272-5928

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Aluminum 24, niobium 11, titanium 65 (atomic) 86666-37-7,
    Aluminum 10, niobium 90 (atomic) 111235-22-4, Aluminum 75,
    niobium 25 (atomic) 119263-46-6 121419-96-3, Aluminum
    50, niobium 50 (atomic) 124307-32-0, Aluminum 25, niobium 25,
    titanium 50 (atomic) 125221-67-2, Aluminum 37.5, niobium 12.5,
    titanium 50 (atomic) 131568-74-6 137322-66-8, Aluminum
    35, niobium 65 (atomic) 158472-85-6 158472-86-7
    RL: PEP (Physical, engineering or chemical process); PROC (Process)
       (synthesis of intermetallics by mech. alloying of)
RN
    51602-53-0 CAPLUS
CN
    Niobium alloy, base, Nb 95, Al 4.9 (9CI) (CA INDEX NAME)
Component
          Component
                        Component
                     Registry Number
           Percent
95
                         7440-03-1
              4.9
                        7429-90-5
   Αl
    60817-72-3 CAPLUS
RN
    Niobium alloy, base, Nb 91, Al 8.8 (9CI) (CA INDEX NAME)
CN
Component
          Component
                        Component
                    Registry Number
          Percent
_______
   Nb
             91
                        7440-03-1
   Al
              8.8
                        7429-90-5
    60817-74-5 CAPLUS
RN
CN
    Niobium alloy, base, Nb 89, Al 11 (9CI) (CA INDEX NAME)
Component
          Component
                        Component
           Percent
                     Registry Number
Nb
             89
                        7440-03-1
   Αl
             11
                        7429-90-5
    78337-79-8 CAPLUS
RN
    Titanium alloy, base, Ti 65,Nb 21,Al 14 (9CI) (CA INDEX NAME)
CN
Component
          Component
                        Component
          Percent
                     Registry Number
=======+===========
   Тi
             65
                         7440-32-6
   Nb
             21
                         7440-03-1
   Al
             14
                         7429-90-5
RN
    86666-37-7 CAPLUS
    Niobium alloy, base, Nb 97, Al 3.1 (9CI) (CA INDEX NAME)
CN
Component
          Component
                       Component
          Percent
                    Registry Number
Nb
            97
                        7440-03-1
   Αl
              3.1
                         7429-90-5
RM
    111235-22-4 CAPLUS
    Niobium alloy, base, Nb 53, Al 47 (9CI) (CA INDEX NAME)
CN
Component
          Component
                        Component
```

```
Registry Number
          Percent
53
                     7440-03-1
   Αl
           47
                     7429-90-5
   119263-46-6 CAPLUS
RN
   Niobium alloy, base, Nb 63, Al 37 (9CI) (CA INDEX NAME)
CN
Component
         Component
                    Component
         Percent
                  Registry Number
63
                     7440-03-1
                     7429-90-5
   A1
           37
    121419-96-3 CAPLUS
RN
CN
   Niobium alloy, base, Nb 77, Al 23 (9CI) (CA INDEX NAME)
Component
         Component
                     Component
         Percent
                 Registry Number
======+==========
   Nb
        77
                     7440-03-1
           23
   Al
                     7429-90-5
    124307-32-0 CAPLUS
RN
CN
   Titanium alloy, base, Ti 44,Nb 43,Al 13 (9CI) (CA INDEX NAME)
Component
         Component
                     Component
         Percent
                 Registry Number
Ti 44
               7440-32-6
   Nb
           43
                     7440-03-1
   Al
          13
                     7429-90-5
RN
    125221-67-2 CAPLUS
   Titanium alloy, base, Ti 52,Nb 25,Al 22 (9CI) (CA INDEX NAME)
CN
Component
         Component
                     Component
         Percent
                 Registry Number
Тi
        52
                     7440-32-6
   Nb
           25
                     7440-03-1
   Αl
           22
                     7429-90-5
RN
    131568-74-6 CAPLUS
    Titanium alloy, base, Ti 43,Nb 42,Al 15 (9CI) (CA INDEX NAME)
CN
Component
         Component
                    Component
         Percent
                 Registry Number
=======+===+====
   Ti
          43
                     7440-32-6
   Nb
           42
                     7440-03-1
   Al
           15
                     7429-90-5
RN
   137322-66-8 CAPLUS
CN
   Niobium alloy, base, Nb 86, Al 14 (9CI) (CA INDEX NAME)
         Component
Component
                    Component
         Percent
                 Registry Number
```

EIC 2800 MARY S. MIMS 272-5928

Nb 86 7440-03-1 Al 14 7429-90-5

RN 158472-85-6 CAPLUS

CN Aluminum alloy, base, Al 62,Nb 38 (9CI) (CA INDEX NAME)

RN 158472-86-7 CAPLUS

CN Niobium alloy, base, Nb 84, Al 16 (9CI) (CA INDEX NAME)

L25 ANSWER 4 OF 7 CAPLUS COPYRIGHT 2006 ACS on STN

```
ACCESSION NUMBER:
                        1995:469055 CAPLUS
DOCUMENT NUMBER:
                        122:271085
TITLE:
                        Synthesis of intermetallics by mechanical alloying
AUTHOR (S):
                        Froes, F. H. (Sam); Suryanarayana, C.; Russell, K.;
                        Li, C.-G.
CORPORATE SOURCE:
                         Institute for Materials and Advanced Processes (IMAP),
                        University of Idaho, Moscow, ID, 83844-3026, USA
SOURCE:
                        Materials Science & Engineering, A: Structural
                        Materials: Properties, Microstructure and Processing
                         (1995), A192/193, 612-23
                         CODEN: MSAPE3; ISSN: 0921-5093
                        Elsevier
PUBLISHER:
DOCUMENT TYPE:
                        Journal
LANGUAGE:
                        English
    Mech. alloying (MA), a solid-state powder processing method, is a 'far
     from equilibrium' synthesis technique which allows the development of novel
     crystal structures and microstructures, leading to enhanced
     phys. and mech. properties. The application of MA to the synthesis of
     intermetallics in the Ti-Al(-Nb), Al-Fe, Nb-Al, Ti-Mg, Al-Zr(-Fe) and
     Al-Mg systems is presented. The ability to synthesize a variety of alloy
     phases, including supersatd. solid solns., nanocryst. structures,
     amorphous phases and intermetallic compds. themselves, is discussed. No
     extension of solubility using MA was observed in the intermetallics studied,
     unlike the situation using rapid solidification (RS). Nanostructured
     grains were observed in all compns., their rate of decrease in size and min.
     size being related to the following partially interrelated parameters:
     stability of the intermetallic, grain boundary energy, m.p. and the
     balance between defect creation/recovery. Long-time milling generally
     resulted in amorphous phase formation largely because of the increase in
     grain boundary energy per mol with reduced grain size; good agreement with
     the Miedema model for amorphization was obtained in the Al-Fe system.
     Generally, annealing was required to form the intermetallic after MA;
     however, intermetallics with a large neg. enthalpy of formation were
     detected in the mech. alloyed condition. Low-temperature compaction allowed
the
     retention of the fine microstructure in the nanometer range,
     giving an interesting capability to enhance ductility in the normally
     brittle intermetallics.
IT
     42611-20-1P 60817-72-3P, Aluminum 25, niobium 75
     (atomic) 111235-22-4P, Aluminum 75, niobium 25 (atomic)
     121419-96-3P, Aluminum 50, niobium 50 (atomic)
     126185-23-7P 132985-48-9P, Aluminum 33, niobium 67
     (atomic) 140678-21-3P 158472-85-6P
     RL: PEP (Physical, engineering or chemical process); PRP (Properties); SPN
     (Synthetic preparation); PREP (Preparation); PROC (Process)
        (mech.-alloyed; amorphous phase formation in)
RN
     42611-20-1 CAPLUS
CN
     Niobium alloy, base, Nb 60, Al 40 (9CI) (CA INDEX NAME)
Component
           Component
                          Component
                       Registry Number
           Percent
Nb
              60
                           7440-03-1
   Al
              40
                           7429-90-5
     60817-72-3 CAPLUS
RN
    Niobium alloy, base, Nb 91, Al 8.8 (9CI) (CA INDEX NAME)
CN
```

EIC 2800 MARY S. MIMS 272-5928

```
Component
         Component
                    Component
         Percent Registry Number
91
                     7440-03-1
   Al
            8.8
                    7429-90-5
RN
   111235-22-4 CAPLUS
CN
   Niobium alloy, base, Nb 53, Al 47 (9CI) (CA INDEX NAME)
Component
         Component
                    Component
         Percent
                 Registry Number
Nb 53 7440-03-1
          47
   Al
                    7429-90-5
RN
   121419-96-3 CAPLUS
CN
   Niobium alloy, base, Nb 77, Al 23 (9CI) (CA INDEX NAME)
Component
         Component
                    Component
         Percent Registry Number
Nb
         77
                    7440-03-1
   Αl
           23
                    7429-90-5
RN
   126185-23-7 CAPLUS
CN
   Niobium alloy, base, Nb 65, Al 35 (9CI) (CA INDEX NAME)
Component
         Component
                    Component
                 Registry Number
         Percent
7440-03-1
   Αl
          35
                    7429-90-5
RN
   132985-48-9 CAPLUS
CN
   Niobium alloy, base, Nb 87, Al 13 (9CI) (CA INDEX NAME)
Component Component
                   Component
        Percent Registry Number
Nb
          87
                    7440-03-1
   Αl
          13
                    7429-90-5
RN
   140678-21-3 CAPLUS
   Niobium alloy, base, Nb 70, Al 30 (9CI) (CA INDEX NAME)
CN
Component
         Component
                    Component
         Percent
                 Registry Number
======+=========+==============
  Nb
          70
                   7440-03-1
  Al
           30
                    7429-90-5
RN
   158472-85-6 CAPLUS
   Aluminum alloy, base, Al 62,Nb 38 (9CI) (CA INDEX NAME)
CN
Component
       Component
                   Component
        Percent Registry Number
62
  Al
                    7429-90-5
```

EIC 2800 MARY S. MIMS 272-5928

Nb 38 7440-03-1

CN Titanium alloy, base, Ti 65,Nb 21,Al 14 (9CI) (CA INDEX NAME)

Component	Component	Component		
	Percent	Registry Number		
======+=	=========	+===========		
Ti	65	7440-32-6		
Nb	21	7440-03-1		
Al	14	7429-90-5		

RN 124307-32-0 CAPLUS

CN Titanium alloy, base, Ti 44,Nb 43,Al 13 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
======+=	=========	+========
Ti	44	7440-32-6
Nb	43	7440-03-1
Al	13	7429-90-5

RN 125221-67-2 CAPLUS

CN Titanium alloy, base, Ti 52,Nb 25,Al 22 (9CI) (CA INDEX NAME)

Component	Component	Component
	Percent	Registry Number
=======+=	===========	=+=========
Ti	52	7440-32-6
Nb	25	7440-03-1
Al	22	7429-90-5

RN 131568-74-6 CAPLUS

CN Titanium alloy, base, Ti 43,Nb 42,Al 15 (9CI) (CA INDEX NAME)

Component	Component	Component	
	Percent	Registry Number	
======+=		=+==========	
Ti	43	7440-32-6	
Nb	42	7440-03-1	
Al	15	7429-90-5	

IT 12003-74-6P 12003-75-7P 12004-70-5P

RL: PNU (Preparation, unclassified); PRP (Properties); PREP (Preparation) (structure and properties of intermetallics in mech.-alloyed Nb-Al system alloys)

RN 12003-74-6 CAPLUS

CN Aluminum, compd. with niobium (1:2) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component		
		Registry Number		
=======================================				
Nb	2	7440-03-1		

Al | 1 | 7429-90-5

RN 12003-75-7 CAPLUS

CN Aluminum, compd. with niobium (1:3) (6CI, 8CI, 9CI) (CA INDEX NAME)

 Component
 Ratio
 Component

 Registry Number

 Nb
 3
 7440-03-1

 Al
 1
 7429-90-5

RN 12004-70-5 CAPLUS

CN Aluminum, compd. with niobium (3:1) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
===========	+=====================================	+=============
Nb	1	7440-03-1
Al	3	7429-90-5

AUTHOR (S):

L25 ANSWER 3 OF 7 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2000:325498 CAPLUS

DOCUMENT NUMBER: 133:20795

TITLE: The effect of excess aluminum on the composition and

microstructure of Nb-Al alloys produced by

aluminothermic reduction of Nb2O5 Ramos, Alfeu S.; Nunes, Carlos A.

CORPORATE SOURCE: Departamento de Engenharia de Materiais, FAENQUIL,

Polo Urbo Industrial, Lorena, 12600-000, Brazil

SOURCE: Journal of Materials Synthesis and Processing (1999),

7(5), 297-301

CODEN: JMSPEI; ISSN: 1064-7562
PUBLISHER: Kluwer Academic/Plenum Publishers

DOCUMENT TYPE: Journal LANGUAGE: English

Intermetallic aluminides including those phases of the Nb-Al system are of interest for high-temperature structural applications. Through aluminothermic reduction (ATR) of Nb2O5 different alloys of the Nb-Al system can be produced by varying the amount of aluminum (excess aluminum) in the thermit charge. In this work, various Nb-Al alloys were produced by varying Nb2O5 and Al powder blends. The resulting alloys were characterized by chemical anal. (Al, O, and C), X-ray diffraction and SEM. The aluminum content of the alloys increased linearly from 14.5 to 50.4 atomic% as the excess Al was varied from 10 up to 60% over the stoichiometric amount to reduce the Nb205. The carbon content was lower than 300 wt-ppm. The oxygen content decreases with increasing excess Al, reaching 1300 wt-ppm for the alloy produced with 60% excess Al. The inclusion content (Al2O3) decreases significantly as the excess Al is increased. The following metallic phases were identified in the alloys: Nbss (niobium solid solution) and Nb3Al (alloy produced with 10% excess Al); Nb3Al (alloys produced with 15 and 20% excess Al); Nb3Al, Nb2Al, and NbAl3 (alloy produced with 30% excess Al); and Nb2Al and NbAl3 (alloys produced with 40, 50, and 60% excess Al).

IT 12003-74-6P 12003-75-7P 12004-70-5P

111235-60-0P, Aluminum 15.4, niobium 84.6 (atomic)

RL: SPN (Synthetic preparation); PREP (Preparation)

(effect of excess aluminum on composition and microstructure of Nb-Al alloys produced by aluminothermic reduction of Nb205)

RN 12003-74-6 CAPLUS

CN Aluminum, compd. with niobium (1:2) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
Nb	2	7440-03-1
Al	1	7429-90-5

RN 12003-75-7 CAPLUS

CN Aluminum, compd. with niobium (1:3) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number	
============	+==============	+======================================	
Nb	3	. 7440-03-1	
Al	1	7429-90-5	

RN 12004-70-5 CAPLUS

CN Aluminum, compd. with niobium (3:1) (6CI, 8CI, 9CI) (CA INDEX NAME)

05/19/2006 10/534703 Thomas

Component	Ratio	Component Registry Number
==========	}=====================================	+=============
Nb	1	7440-03-1
Al	3	7429-90-5

RN 111235-60-0 CAPLUS

CN Niobium alloy, base, Nb 95, Al 5 (9CI) (CA INDEX NAME)

Component	Component	Component	
	Percent	Registry Number	
======+=		+=========	
Nb	95	7440-03-1	
Al	5	7429-90-5	

REFERENCE COUNT:

15 THERE ARE 15 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT L25 ANSWER 2 OF 7 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2000:701723 CAPLUS

DOCUMENT NUMBER: 134:24348

TITLE: RF magnetron sputtering target for Nb3Al made by

powder metallurgy

AUTHOR(S): Agatsuma, K.; Tateishi, H.; Arai, K.; Saitoh, T.;

Futaki, N.

CORPORATE SOURCE: Electrotechnical Laboratory, Ibaraki, Japan

SOURCE: Institute of Physics Conference Series (2000),

167 (Applied Superconductivity 1999, Vol. 1), 1179-1182

CODEN: IPCSEP; ISSN: 0951-3248

PUBLISHER: Institute of Physics Publishing

DOCUMENT TYPE: Journal LANGUAGE: English

AB The authors have attempted to make a single target out of the mixed powder of Nb and stable Nb-Al compound powder to avoid difference in stoichiometry. The authors use a stable Nb-Al compound, which consists of the pressed powder of Nb and NbAl3, or Nb2Al mixture Thin Nb3Al films on MgO and Al2O3 substrate were made using these targets. The thin films on MgO and Al2O3 substrate made with these targets show supercond. The exptl. results are presented.

IT 7440-03-1, Niobium, processes 12003-74-6 12003-75-7 12004-70-5

RL: PEP (Physical, engineering or chemical process); TEM (Technical or engineered material use); PROC (Process); USES (Uses)

(RF magnetron sputtering target for Nb3Al made by powder metallurgy)

RN 7440-03-1 CAPLUS

CN Niobium (8CI, 9CI) (CA INDEX NAME)

Nb

RN 12003-74-6 CAPLUS

N Aluminum, compd. with niobium (1:2) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
Nb	2	.7440-03-1
Al	1	7429-90-5

RN 12003-75-7 CAPLUS

CN Aluminum, compd. with niobium (1:3) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
Nb Al	+=====================================	7440-03-1 7429-90-5

RN 12004-70-5 CAPLUS

CN Aluminum, compd. with niobium (3:1) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number	
=======================================	}=====================================		
Nb	1	7440-03-1	

05/19/2006 10/534703 Thomas

Al | 3 | 7429-90-5

REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L25 ANSWER 1 OF 7 CAPLUS COPYRIGHT 2006 ACS on STN

ACCESSION NUMBER: 2002:408022 CAPLUS

DOCUMENT NUMBER: 137:188911

TITLE: Microstructural analysis and mechanical properties of

in situ Nb/Nb-aluminide layered materials

AUTHOR(S): Chung, Dong-Seok; Enoki, Manabu; Kishi, Teruo

CORPORATE SOURCE: Department of Materials, Changwon Polytechnic College,

Changwon, Kyungnam, 641-772, S. Korea

SOURCE: Science and Technology of Advanced Materials (2002),

3(2), 129-135

CODEN: STAMCV; ISSN: 1468-6996

PUBLISHER: Elsevier Science Ltd.

DOCUMENT TYPE: Journal LANGUAGE: English

AB Thin foil hot press process was developed for manufacturing metal/intermetallic compound laminate composites to induce self-propagating high-temperature synthesis

(SHS) reaction between different pure metal sheets. In the present work, Nb/Nb-aluminide laminate composites were manufactured with pure Nb and Al sheets, which consist of fine Nb/Nb2Al/NbAl3 or Nb/Nb3Al/Nb2Al/NbAl3 layer structure. Microvickers hardness test and energy dispersive x-ray spectroscopy (EDS) anal. in the intermetallic compound layer demonstrate the formation of various phases, and the microvickers hardness values decrease with increasing Al/Nb atomic ratio. Although the tensile strength of laminate composites is similar to pure Nb, ductility and fracture toughness are significantly improved due to plastic deformation in Nb layer.

IT 12003-74-6 12003-75-7 12004-70-5

RL: FMU (Formation, unclassified); PRP (Properties); FORM (Formation, nonpreparative)

(microstructural anal. and mech. properties of in situ Nb/Nb-aluminide layered materials)

RN 12003-74-6 CAPLUS

CN Aluminum, compd. with niobium (1:2) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
Nb	2	7440-03-1
Al	1	7429-90-5

RN 12003-75-7 CAPLUS

CN Aluminum, compd. with niobium (1:3) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number
Nb	3	7440-03-1
Al	1	7429-90-5

RN 12004-70-5 CAPLUS

CN Aluminum, compd. with niobium (3:1) (6CI, 8CI, 9CI) (CA INDEX NAME)

Component	Ratio	Component Registry Number .
=======================================	+=====================================	+=========
Nb	1	7440-03-1
Al	3	7429-90-5

IT 7440-03-1, Niobium, properties 37254-86-7

RL: PRP (Properties)

(microstructural anal. and mech. properties of in situ Nb/Nb-aluminide layered materials)

RN 7440-03-1 CAPLUS

CN Niobium (8CI, 9CI) (CA INDEX NAME)

Nb

RN 37254-86-7 CAPLUS

CN Aluminum alloy, base, Al 0-100, Nb 0-100 (9CI) (CA INDEX NAME)

Component	Com	ponent	Compon	.ent
	Pe	rcent	Registry	Number
======+=	====	=======	+======	=====
Al	0	- 100	7429-	90-5
Nb	0	- 100	7440-	03-1

REFERENCE COUNT: 43 THERE ARE 43 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

INTERNATIONAL SEARCH REPORT

International application No.
PCT/JP03/14556

	FICATION OF SUBJECT MATTER 17 B22F1/00			
According to 1	International Patent Classification (IPC) or to both na	tional classification and IPC		
B. FIELDS	SEARCHED			
Minimum doc	cumentation searched (classification system followed	by classification symbols)		
Int.C	1 ⁷ B22F1/00			
Documentatio	on searched other than minimum documentation to the	extent that such documents are included	in the fields searched	
Jitsuy		Toroku Jitsuyo Shinan Koho Jitsuyo Shinan Toroku Koho	1994-2002	
Electronic dat	a base consulted during the international search (nam	e of data base and, where practicable, sear	ch terms used)	
C. DOCUM	ENTS CONSIDERED TO BE RELEVANT			
Category*	Citation of document, with indication, where ap	propriate, of the relevant passages	Relevant to claim No.	
Y .	JP 60-066806 A (Nippon Conde	nser Kogyo Kabushiki	1-14	
	<pre>Kaisha), 17 April, 1985 (17.04.85),</pre>			
	Claims; page 2, lower right of	column; page 3, upper		
	right column			
	(Family: none)			
Y	JP 01-124212 A (Nichicon Cor	, (, c	1-14	
_	17 May, 1989 (17.05.89),			
	Claims; page 2, lower part; p	page 3, upper left		
	column			
	(Family: none)	İ		
Y	US 3564348 A (Sprague Electr		1-14	
	16 February, 1971 (16.02.71),			
	Column 2, lines 24 to 30 (Family: none)	· 1		
	(
× Further	documents are listed in the continuation of Box C.	See patent family annex.		
* Special categories of cited documents: "I" later document published after the internation document defining the general state of the art which is not priority date and not in conflict with the applications.			e application but cited to	
"E" carlier do	ed to be of particular relevance ocument but published on or after the international filing	"X" understand the principle or theory und document of particular relevance; the	claimed invention cannot be	
	date considered novel or cannot be considered to involve an inventive step when the document is taken alone			
cited to establish the publication date of another citation or other special reason (as specified) "O" document referring to an oral disclosure, use, exhibition or other combined with one or more other such documents, such				
means combination being obvious to a person skilled in the art "P" document published prior to the international filing date but later "&" document member of the same patent family than the priority date claimed				
Date of the ac	tual completion of the international search	Date of mailing of the international search	ch report	
10 December, 2003 (10.12.03) 24 December, 2003 (24.12.03)				
Name and mailing address of the ISA/ Authorized officer .				
Japanese Patent Office				
Facsimile No.		Telephone No.		

United States Patent

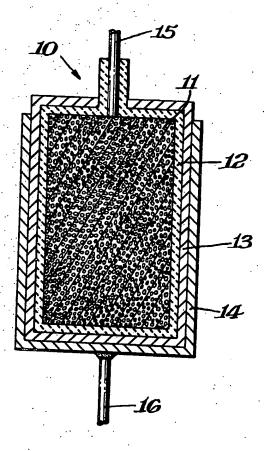
[11] 3,564,348

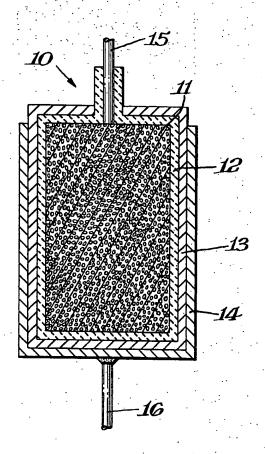
[72]	Inventor	David M. Cheseldine Bennington, Vt.	
[21]	Appl. No.	814,089	•
(22)	Filed	Apr. 7, 1969	
[45]		Pob 14 1074	•
[73]			
[13]	Assignee	Sprague Electric Company	•
		North Adams, Mass.	
		a corporation of Massachusetts	
	3 Claims, 1	I-ANTIMONY ALLOY ELECTR CAL CAPACITOR Drawing Fig.	ODE
[52]	U.S. Cl		317/230,
[51]			317/238
[50]	Elit CL	rch	H01g 9/05
[20]	rield of Sea	rch	317/230,
		231,232	, 233, 258
		•	

[26]		References Cited	
•	UNI	TED STATES PATENTS	
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2,504,178	4/1950	Rumbon or al	317/230
3,098,182	7/1963		317/230
3,126,503	3/1964	Burnham	317/230
3,255,389	6/1966	Colomon at 1	317/230
3,270,261	8/1966	Salomon et al	317/230
Driman. F.			317/230
· r runary Ex	aminer J:	ames D. Kallam	

Attorneys—Connolly and Hutz, Vincent H. Sweeney, James Paul O'Sullivan and David R. Thornton

ABSTRACT: An electrical capacitor is provided having at least one electrode comprising an alloy of titanium and antimony. An antimony concentration of 10 to 30 percent by weight provides an electrode material on which a stable anodic film is grown, such film being characterized by good thermal and electrical stability.





TITANIUM-ANTIMONY ALLOY ELECTRODE **ELECTRICAL CAPACITOR**

BACKGROUND OF THE INVENTION

This invention relates to electrolytic capacitors and more particularly to a capacitor having an anodic oxide dielectric formed on an alloy of titanium and antimony.

Heretofore, the elemental metals aluminum and tantalum have been widely used as dielectric oxide film-forming electrodes in the making of electrolytic capacitors. Tantalum oxide has a high dielectric constant and hence high capacity per unit area, good mechanical strength and excellent chemical resistance for both oxide and metal. However, tantalum has the disadvantage of relatively high cost and greater weight.

Aluminum is low in cost, has a low density and is easily etched to increase the surface area. However, aluminum has a relatively lower dielectric constant, poorer mechanical strength and lower resistance to corrosion than tantalum.

While anodic films may be grown on many other materials, 20 none are presently being used in making electrolytic capacitors because of poor electrical and thermal stability of the films produced. Titanium is one of the materials considered for such use in view of the high dielectric constant of its oxide and its good corrosion resistance, low density and relatively 25 low cost. However, it has been found that continuous oxide films for dielectric purposes cannot readily be formed to acceptable voltage levels on the titanium metal by conventional anodizing methods such as used in connection with aluminum and tantalum. For example, during the anodization, the film 30 stops growing uniformly and gas evolution occurs at points on the surface at voltages well below 100 volts. Furthermore, even when an electrolyte does form higher voltage films the dielectric films are not electrically stable. They exhibit a tendency for capacity to increase with time and to show a strong 35 dependence on bias voltage.

In an attempt to form oxides at higher voltage levels, various elements such as palladium, niobium, tantalum, tin, boron, vanadium, chromium and aluminum have been alloyed with titanium but the anodic films formed on such alloys usually suffer from one or more defects such as instability with heat or DC bias, high dissipation factors or high leakage current.

It is therefore an object of the present invention to provide capacitors having electrodes which can be anodized to form dielectric films without the above cited disadvantages.

It is another object to provide an electrode for such a capacitor on which anodic films may be grown over a wide range of thicknesses.

SUMMARY OF THE INVENTION

Broadly this invention concerns electric capacitors having novel anodic film-forming electrodes. More particularly, such electrodes comprise an alloy of titanium and antimony. It has been found that a stable anodic film can be grown on such an 5 alloy composition thereby providing films having relatively high capacity compared to aluminum oxide but somewhat below that of tantalum oxide. An optimum titanium composition by weight has been found to fall within 70 to 90 percent. The alloy composition is considerably cheaper and lighter 60 than tantalum yet offers comparable mechanical strength and chemical resistance; the anodic films formed thereon can be produced in conventional aqueous electrolytes or in organic electrolytes. These films are further characterized by uniform interference colors, high breakdown voltages, low electronic leakage currents and low dissipation factors.

BRIEF DESCRIPTION OF THE DRAWING

which the novel electrode is embodied.

DETAILED DESCRIPTION OF THE INVENTION

In accordance with the present invention, an alloy of titani-

alloy is then processed, using standard metallurgical techniques, to the required anode shape depending on the form of the capacitor it is desired to make. Common forms of electrolytic capacitors use anodes shaped as thin foils, wires or pellets consisting of sintered particles. The shaped alloy is then anodized in any suitable electrolyte to form the highquality dielectric film which is a feature of the invention. The capacitor unit may be completed by combination with a "wet" or "solid" electrolyte and by adding another electrode.

Referring to the drawing, there is shown a solid electrolyte capacitor 10 with an anode 11 composed of the sintered titanium alloy of (80 invention as 20 more fully described. A dielectric oxide film 12 is formed on the surface of the anode and a coating 13 of a suitable solid electrolyte such as manganese dioxide overlies dielectric oxide film 12. The cathode electrode 14 is formed by coating the outer surface of the electrolyte with an appropriate metal such as silver. A film-forming lead wire 15 made from the alloy or any other film-forming metal contacts anode 11. A cathode lead 16 is suitably joined by welding or otherwise connecting the lead to electrode 14. The entire unit is then encapsulated with a preferred sealant (not shown).

The alloy of which anode 11 is composed was prepared in an arc furnace by mixing the powders of the constituent metals (80 percent titanium, 20 percent antimony by weight in this embodiment) and melting the mixture in an inert atmosphere by striking an arc between a mobile tungsten electrode and the powder mixture. The anode is formed by wellknown powder metallurgy techniques wherein the spherical particles of the alloy are compressed and sintered into a compact mass.

Other means of preparing the alloy are available however, e.g. vacuum induction melting and sintering. The method of alloy preparation does not constitute any part of this inven-

Tests have been made to determine the characteristics of alloys of differing composition than the example above. It has been found that a composition comprising above 90 percent by weight of titanium, while anodizing to a higher voltage than pure titanium, formed less stable films. At 70 percent by weight of titanium, the composition gave a rather nonhomogeneous alloy on which it was difficult to obtain a good surface. On compositions comprising less than 70 percent of titanium, the alloy tended to become brittle and to crack during solidification. An optimum composition range would therefore be 70 to 90 percent by weight of titanium.

The following examples illustrate the dielectric properties of anodic films which may be formed on an alloy containing 20 percent of antimony.

The alloy was anodized to 90 volts in an aqueous solution of 10 percent phosphorous acid at 25° C. using a current density of 0.6 ma./cm2. Almost any other electrolyte may be used which does not attack the film and which is sufficiently dilute so that the oxide film does not break down due to scintillation at the anodizing voltage. The final voltage was held for 45 minutes until the current decayed to 15 µa/cm². When measured in a solution of 10 percent ammonium dihydrogen phosphate, the film showed a capacity of 0.14 μ f/cm² or a capacity voltage product (CV) of 12.5 µf-v./cm2. This compares with a CV of about 14 μ f-v./cm² for tantalum and 6.5 μ fv./cm² for aluminum. The dissipation factor in the same solution was 1.2 percent at 120 cycles. The electrode was then immersed for a period of 1 month in a working electrolyte at 85°. and 47 VDC applied against a tantalum cathode. After an initial period of 3 days the leakage current stabilized at a steady value of about $3 \times 10^{-3} \mu a/cm^2$. Periodic measurements of The sole drawing shows a solid electrolyte capacitor in 70 The dissipation factor remained at about 1 percent while the capacity and dissipation factor showed no significant changes. change in capacity, measured both at zero and 50 VDC bias, was less than 3 percent.

As a further example the alloy of the present invention was anodized in 0.01 MH₂PO₄ at voltages up to 350 v. The film um and antimony is prepared by any preferred means. This 75 formed at the upper end of the voltage range still showed a

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bright interference color with no noticeable surface gas evolution. By comparison, titanium anodized under similar conditions broke down at about 20 v. and showed irregular interference colors and gas evolution prior to breakdown.

While the above example has described a capacitor having a sintered anode formed of the described alloy mixture, it is understood that the novel electrode could be formed as a foil or wire depending upon the capacitor configuration and use. And instead of a solid electrolyte any preferred "wet" electrolyte solution may be used and enclosed within the appropriate casing.

I claim:

1. An electrical capacitor comprising spaced electrodes, at

least one of said electrodes being an alloy of titanium and antimony, said at least one electrode having an anodic dielectric oxide film formed thereon and disposed between said electrodes.

2. A capacitor as described in claim 1 wherein titanium is present in the alloy in the amount of 70—90 percent by weight.

3. A capacitor as described in claim 1 wherein said at least one electrode is a sintered mass of particles of said alloy and wherein a layer of semiconductive material overlies said dielectric oxide film.

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UNITED STATES PATENT OFFICE CERTIFICATE OF CORRECTION

Patent No.	3,564,348	Dated	February	16,	1971

Inventor(s) David M. Cheseldine

It is certified that error appears in the above-identified patent and that said Letters Patent are hereby corrected as shown below:

Column 2, line 12, omit "(80 invention as 20" and insert -- the invention as hereinafter --

Column 2, line 65, change "850" to -- 85°C -- Column 3, line 3, change "20" to -- 70 --

Signed and sealed this 13th day of July 1971.

(SEAL) Attest:

EDWARD M.FLETCHER, JR. Attesting Officer

WILLIAM E. SCHUYLER, JR. Commissioner of Patents